# NSN 5961-00-629-2513

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### **Inclosure Material:**

Metal

### **Overall Length:**

Between 0.250 inches and 0.450 inches

# **Overall Diameter:**

0.875 inches

### **Mounting Facility Quantity:**

2

### Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

### **Mounting Method:**

Unthreaded hole

Features Provided:

### Hermetically sealed case

### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

# Current Rating Per Characteristic:

Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current

### Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

### **Special Features:**

Junction pattern arrangement: pnp

### Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

2 pin and 1 case

### **Specification Data:**

81349-mil-s-19500/379 government specification

### Shelf Life:

N/a

### Unit Of Measure:

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### Demilitarization:

No

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